





Features

- UL Recognized File # E-326243
- Plastic material used carries Underwriters Laboratory Classifications 94V-0
- Metal silicon junction, majority carrier conduction

- Low power loss, high efficiency
 High current capability, low forward voltage drop
 High surge capability
 For use in low voltage, high frequency inverters,
- free wheeling, and polarity protection applications Guardring for overvoltage protection
 High temperature soldering guaranteed:
 260°C/10 seconds,0.25"(6.35mm) from case
- Green compound with suffix "G" on packing code & prefix "G" on datecode.

Mechanical Data

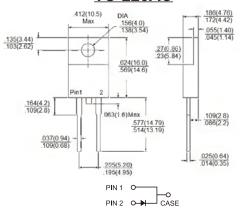
- Cases: JEDEC TO-220AC molded plastic body
- Terminals: Pure tin plated, lead free. solderable per MIL-STD-750, Method 2026 Polarity: As marked

- Mounting position: Any Mounting torque: 5 in. lbs. max
- Weight: 1.86 grams

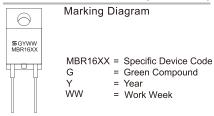
MBR1635 - MBR16150

16.0 AMPS. Schottky Barrier Rectifiers

TO-220AC



Dimensions in inches and (millimeters)



Maximum Ratings and Electrical Characteristics
Rating at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%

Type Number	Symbol	MBR 1635	MBR 1645	MBR 1650	MBR 1660	MBR 1690	MBR 16100	MBR 16150	Units
Maximum Recurrent Peak Reverse Voltage	Vrrm	35	45	50	60	90	100	150	V
Maximum RMS Voltage	VRMS	24	31	35	42	63	70	105	V
Maximum DC Blocking Voltage	VDC	35	45	50	60	90	100	150	V
Maximum Average Forward Rectified Current at Tc=125°C	I F(AV)	16							Α
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20KHz) at Tc=125°C	I FRM	32							Α
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	IFSM	150							Α
Peak Repetitive Reverse Surge Current (Note 2)	IRRM	1.0 0.5						Α	
Maximum Instantaneous Forward Voltage at: I _F =16A, T _A =25°C I _F =16A, T _A =125°C	VF	0.63 0.57			75 0.8 65 0.7			0.95 0.92	V
Maximum Instantaneous Reverse Current at Rated DC Blocking Voltage (Note 1)@Ta =25 °C @ Ta =125 °C	I R		.5 5	1	.5 0	1	.3 .5	0.1 5	mA mA
Voltage Rate of Change (Rated V _R)	dV/dt	10,000							V/uS
Typical Junction Capacitance	Cj	500							pF
Maximum Typical Thermal Resistance(Note 3)	Rejc	3.0							°C/W
Operating Junction Temperature Range	TJ	-65 to +150							°C
Storage Temperature Range	Tstg	-65 to +175							°C

Notes: 1. Pulse Test: 300us Pulse Width, 1% Duty Cycle

2. 2.0us Pulse Width, f=1.0 KHz

3. Mount on Heatsink Size of 2" x 3"x 0.25" Al-Plate.

Version: F10



RATINGS AND CHARACTERISTIC CURVES (MBR1635 THRU MBR16150)

